



About      = Input Box

TERMS OF USE

## Step 1: Operating Specifications

LM5143A-Q1

Single Output - 4 Phases    
**Input Voltage - Min,  $V_{IN(min)}$**  30 V   
**Input Voltage - Nom,  $V_{IN(nom)}$**  49 V   
**Input Voltage - Max,  $V_{IN(max)}$**  50 V   
**Output Voltage,  $V_{OUT}$**  15 V   
**Full Load Output Current,  $I_{OUT}$**  70 A   
**Switching Frequency,  $F_{SW}$**  2200 kHz   
**Frequency Set Resistor,  $R_T$**  10 kΩ   
**Ambient Temperature,  $T_A$**  25 °C

## Step 2: Current Sense Resistors

Shunt current sensing

**Required  $I_{OC}$  Setpoint at  $V_{IN(nom)}$**  30 A   
**Recommended Sense Resistance** 7.4 mΩ   
**Sense Resistance,  $R_S$**  2 mΩ   
**Min Inductor Sat Current,  $I_{C(SAT)}$**  36.5 A   
**Max power loss in shunt** 2.42 W   
 $V_{A(max)}$  139.2 A   
 $I_{OUT(typ)}$  at OCP Inception:  $V_{A(nom)}$  136.5 A   
 $V_{A(max)}$  136.4 A

## Step 3: Buck Inductances

**Ch1 Recommended Inductance** 0.57 μH   
**Ch1 Inductance,  $L_{O1}$**  1 μH   
**Ch1 Inductor DCR** 2 mΩ   
 $\Delta I_L$  as a % at  $V_{IN(nom)}$  27 %

## Step 4: Output Capacitors

**Output Voltage Ripple Spec** 400 mV<sub>pk-pk</sub>   
**Minimum Output Capacitance** 2.2 μF   
**Output Capacitance (derated),  $C_{OUT}$**  580 μF   
**Maximum Permitted ESR** 84 mΩ   
**Output Capacitor ESR** 3 mΩ   
**Resulting Output Voltage Ripple (max)** 14 mV<sub>pk-pk</sub>   
**Output Capacitor RMS Current (max)** 1.38 A (rms)

## Step 5: Input Capacitors

**Input Voltage Ripple Spec** 2500 mV<sub>pk-pk</sub>   
**Minimum Input Capacitance** 10 μF   
**Input Capacitance,  $C_{IN}$**  20.047 μF   
**Maximum Permitted ESR** 120.7 mΩ   
**Input Capacitor ESR** 1 mΩ   
**Resulting Input Voltage Ripple (max)** 119 mV<sub>pk-pk</sub>   
**Input Capacitor RMS Current (max)** 8.75 A (rms)

## Step 6: Soft-start, Hiccup, Dither, DEMB, MODE

**Soft-Start Time,  $t_{SS}$**  3 ms   
**Soft-Start Capacitance,  $C_{SS}$**  100 nF   
**Hiccup Fault Time,  $t_{HCC}$**  12 ms   
**RES Capacitance,  $C_{RES}$**  220 nF

DITHER Disabler

FPWM

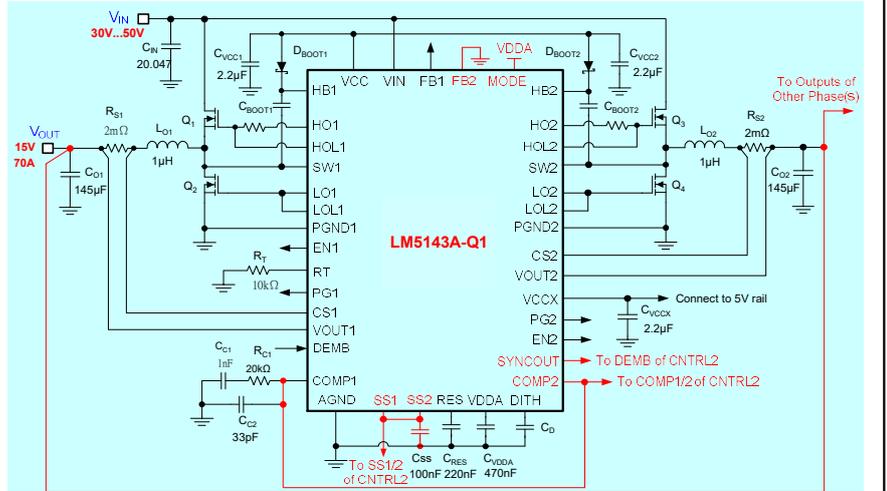
- \*Tie DITH to VDDA
- \*Tie DEMB to VDDA
- \*Tie MODE to VDDA

## Step 7: Compensation Design

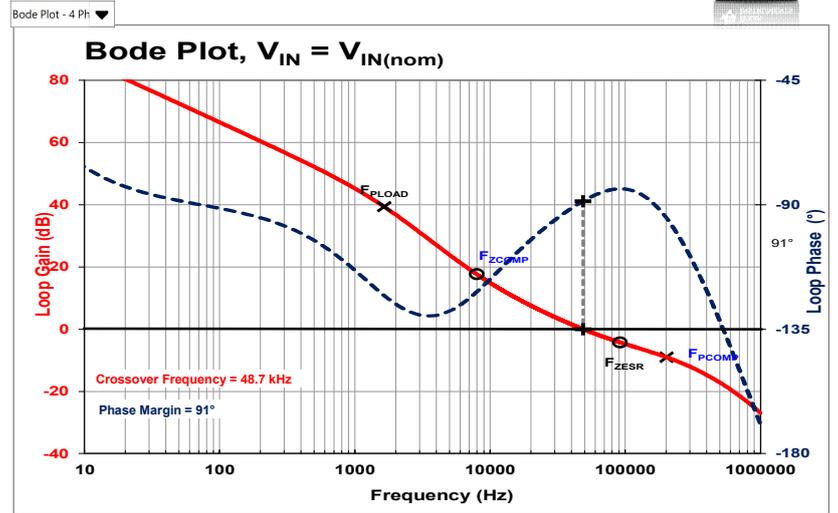
**Load Pole Frequency** 1648 Hz   
**ESR Zero Frequency** 91 kHz   
**Desired Crossover Frequency** 60 kHz   
**Error Amp Pole Frequency** 2.5 Hz   
**Upper Feedback Resistor** 240 kΩ   
**Lower Feedback Resistor** 10 kΩ

## Compensation Components

	Calculated / Std Values	Std Values	Actual P/Z Frequencies
$R_{C1}$	27.3 / 27.4	20 kΩ	2 Hz ( $F_{FEA}$ )
$C_{C1}$	1.0 / 1	1 nF	8.0 kHz ( $F_{ZCOMP}$ )
$C_{C2}$	57 / 56	33 pF	202 kHz ( $F_{POCOMP}$ )



\*\* For Single-Output Operation in 4-Phase Mode, tie both MODE pins to VDDA. Use FB1 of master IC to set VOUT. Connect FB2 of slave IC to VDDA to configure it as a slave \*\*   
 \*\* Slave controller (CNTRL2) not shown \*\*   
 \*\* Tie VCCX to GND if not used \*\*



\*\* Specify Inductor Core Loss \*\* 0.3 W

## Efficiency / Power Loss Analyzer

### Step 8: Efficiency

Efficiency vs. IOUT - 4 Ph

Power MOSFETs  
ISC0805NLS, ISC0805NLS

	High-side	Low-side
On-State Resistance, $R_{DS(on)}$	9.0	9.0
Total Gate Charge, $Q_G$	13	13
Gate-Drain Charge, $Q_{GD}$	4.7	4.7
Gate-Source Charge, $Q_{GS}$	6	6
Output Charge, $Q_{OSS}$		34
Output Capacitance, $C_{OSS}$	280	280
Gate Resistance, $R_G$	1	1
Transconductance, $g_{RS}$	73	73
Gate-Source Threshold Voltage, $V_{TH}$	1.6	1.6
Body Diode Forward Voltage, $V_{SD}$	0.92	0.92
Body Diode Rev Recovery Charge, $Q_{RR}$		28
Thermal Resistance, $\theta_{JA}$	50	50

### External Schottky Diode (if applicable)

Schottky Fwd Voltage, $V_{FSDsch}$	0.46	V
Schottky Rev Recovery Charge, $Q_{RRsch}$	1.5	nC

### Step 9: IC Power Loss

VCCX Connected <input type="checkbox"/>	IC Power Dissipation	0.57 W
	IC Junction Temperature (estimate)	44.9 °C

